RG10GGF

SINTERED GLASS JUNCTION FAST SWITCHING PLASTIC RECTIFIER VOLTAGE: 400 V CURRENT: 1.2A

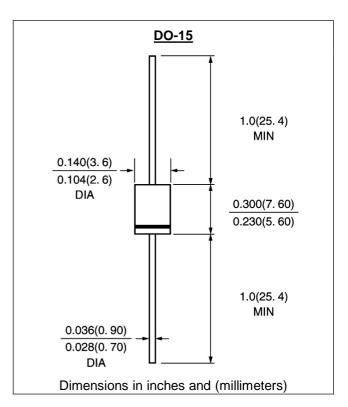


FEATURE

High temperature metallurgic ally bonded construction Sintered glass cavity free junction Capability of meeting environmental standard of MIL-S-19500 High temperature soldering guaranteed 350° C /10sec/0.375"lead length at 5 lbs tension Operate at Ta =60°C with no thermal run away Typical Ir<0.2 μ A Low power loss, high efficient

MECHANICAL DATA

Terminal: Plated axial leads solderable per MIL-STD 202E, method 208C Case: Molded with UL-94 Class V-0 recognized Flame Retardant Epoxy Polarity: color band denotes cathode Mounting position: any



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(single-phase, half-wave, 60HZ, resistive or inductive load rating at 25°C, unless otherwise stated)

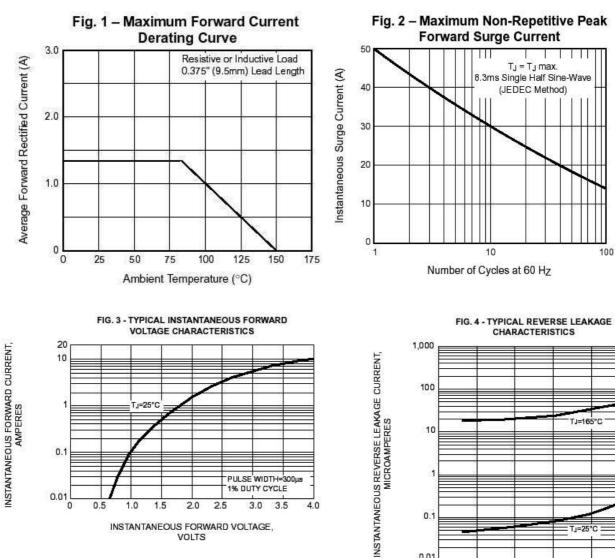
	SYMBOL	RG10GGF	units
Maximum Recurrent Peak Reverse Voltage	Vrrm	400	V
Maximum RMS Voltage	Vrms	280	V
Maximum DC blocking Voltage	Vdc	400	V
Maximum Average Forward Rectified Current 3/8"lead length at Ta =60°C	lf(av)	1.2	А
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	lfsm	50	А
Maximum Forward Voltage at IF=1.5A and 25°C	Vf	1.2	V
Maximum DC Reverse CurrentTa = $25^{\circ}C$ at rated DC blocking voltageTa = $125^{\circ}C$	Ir	10 100	μΑ μΑ
Maximum Reverse Recovery Time (Note 1)	Trr	50	nS
Typical Junction Capacitance (Note 2)	Cj	33	pF
Typical Thermal Resistance (Note 3)	R(ja)	20	°C /v
Storage and Operating Temperature Range	Tstg, Tj	-65 to +175	°C

Note:

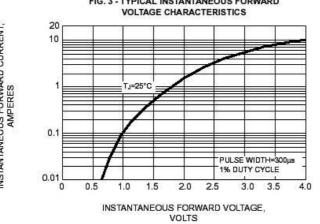
1. Reverse Recovery Condition If =0.5A, Ir =1.0A, Irr =0.25A

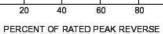
2. Measured at 1.0 MHz and applied reverse voltage of 4.0Vdc

3. Thermal Resistance from Junction to Ambient at 3/8"lead length, P.C. Board Mounted



RATINGS AND CHARACTERISTIC CURVES RGI0GGF





TJ=25°C

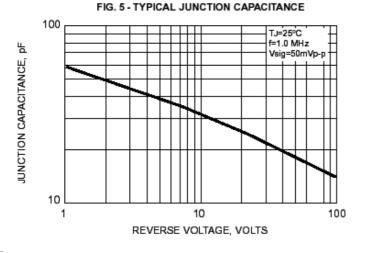
100

0.1

0.01

0

VOLTAGE, %



1

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